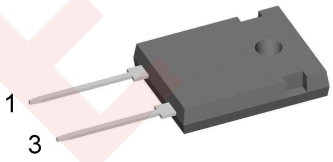
Sonic Fast Recovery Diode

V_{RRM} = 1600 V
I_{FAV} = 60 A
t_{rr} = 230 ns

High Performance Fast Recovery Diode
Low Loss and Soft Recovery
Single Diode

Part number

DH60-16A



Backside: cathode



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Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

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Fast Diode

Symbol	Definition	Conditions		Ratings min.	typ.	max.	Unit
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			1600	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			1600	V
I_R	*reverse current, drain current*	V_R = 1600 V	T_{VJ} = 25°C			200	µA
		V_R = 1600 V	T_{VJ} = 125°C			2	mA
V_F	*forward voltage drop*	I_F = 60 A	T_{VJ} = 25°C			2.04	V
		I_F = 120 A				2.57	V
		I_F = 60 A	T_{VJ} = 125°C			2.03	V
		I_F = 120 A				2.73	V
I_{FAV}	*average forward current*	T_C = 100°C rectangular d = 0.5	T_{VJ} = 150°C			60	A
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 150°C			1.28	V
r_F	*slope resistance* }					12	mΩ
R_{thJC}	*thermal resistance junction to case*					0.3	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.3		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			415	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine; V_R = 0 V	T_{VJ} = 45°C			700	A
C_J	*junction capacitance*	V_R = 1200 V f = 1 MHz	T_{VJ} = 25°C		32		pF
I_{RM}	*max. reverse recovery current*		T_{VJ} = 25°C		60		A
		I_F = 60 A; V_R = 1200 V	T_{VJ} = 100°C		70		A
t_{rr}	*reverse recovery time*	$-di_F/dt$ = 800 A/µs	T_{VJ} = 25°C		230		ns
			T_{VJ} = 100°C		350		ns

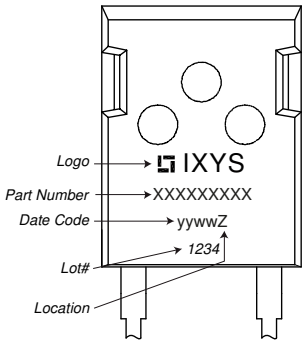
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Package TO-247			Ratings			
Symbol	**Definition**	**Conditions**	**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal			70	A
T_{VJ}	*virtual junction temperature*		-55		150	°C
T_{op}	*operation temperature*		-55		125	°C
T_{stg}	*storage temperature*		-55		150	°C
Weight				6		g
M_D	*mounting torque*		0.8		1.2	Nm
F_C	*mounting force with clip*		20		120	N

Product Marking

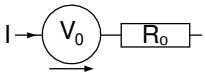


Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DH60-16A	DH60-16A	Tube	30	496545

Similar Part	Package	Voltage class
DH60-14A	TO-247AD (2)	1400
DH60-18A	TO-247AD (2)	1800

Equivalent Circuits for Simulation

** on die level* $T_{VJ} = 150°C$

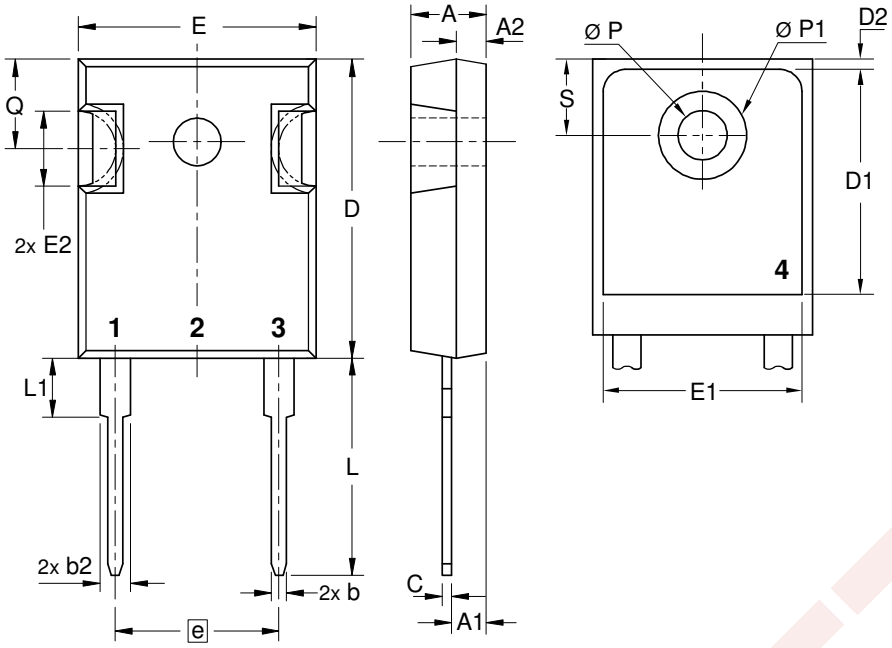


		Fast Diode	
$V_{0\,max}$	*threshold voltage*	1.28	V
$R_{0\,max}$	*slope resistance **	9.5	mΩ

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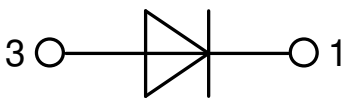
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Outlines TO-247



Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.430 BSC		10.92 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39

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Fast Diode

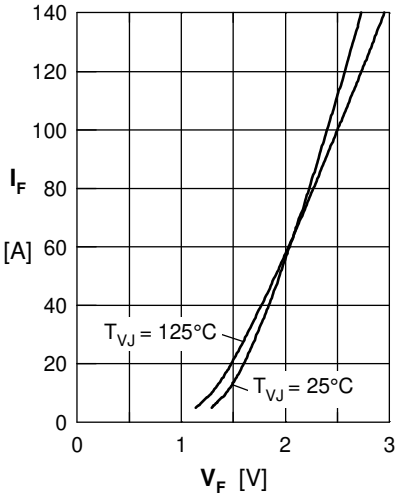


Fig. 1 Typ. forrward current I_F versus V_F

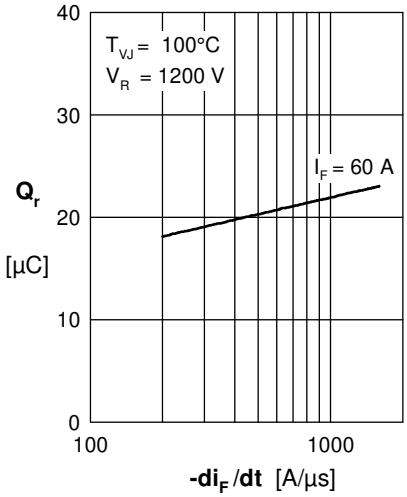


Fig. 2 Typ. reverse recovery charge Q_r versus $-di_F/dt$

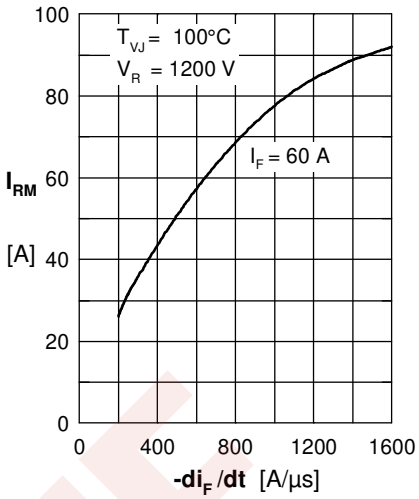


Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

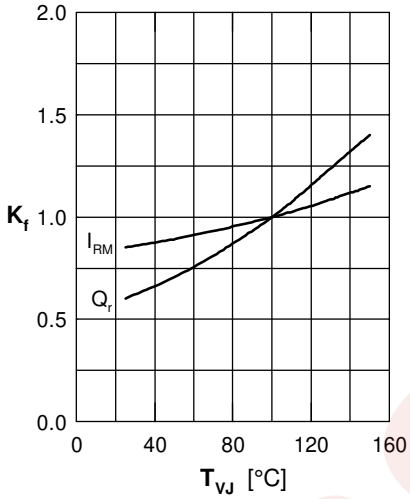


Fig. 4 Dynamic parameters Q_r, I_{RM} versus T_{VJ}

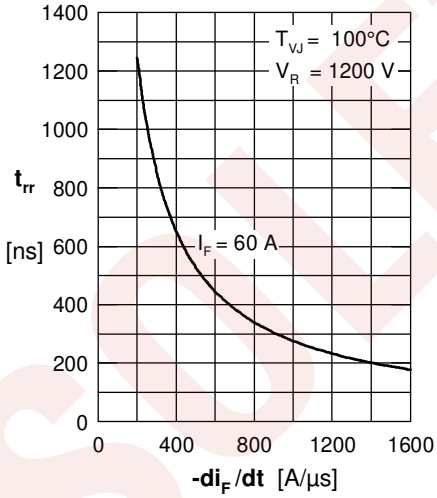


Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$

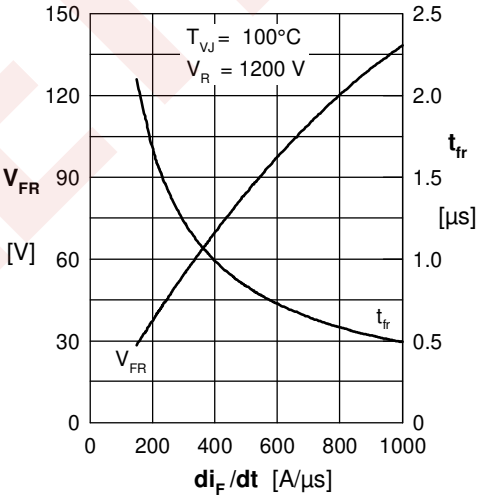
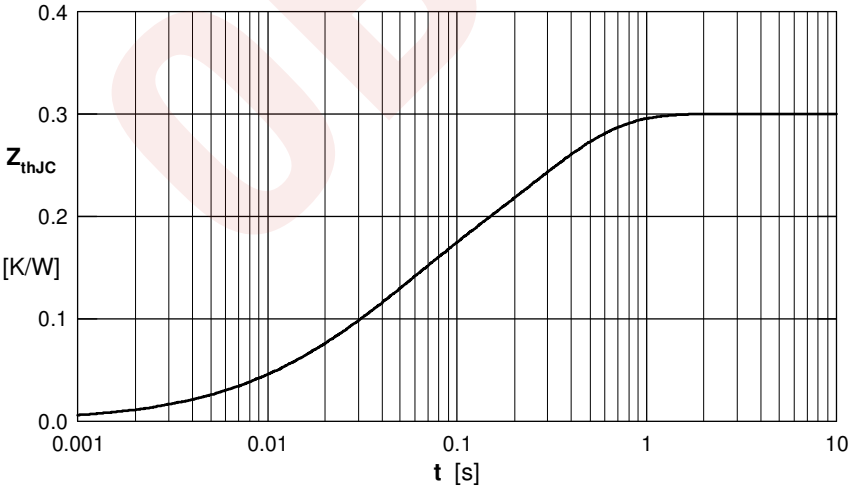


Fig. 6 Typ. peak forward voltage V_{FR} & typ. forward recovery time t_{fr} versus di_F/dt



i	R_i	τ_i
1	0.021	0.0093
2	0.11	0.038
3	0.169	0.274

Fig. 7 Transient thermal resistance junction to case

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